



Digital transistors (built-in resistors)

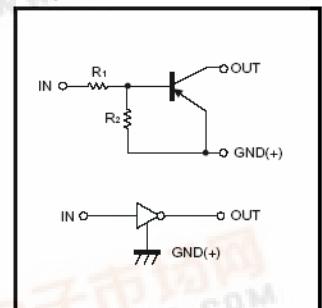
DTA114YE/DTA114YUA/DTA114YKA/ DTA114YSA/DTA114YCA

DIGITAL TRANSISTOR (PNP)

FEATURES

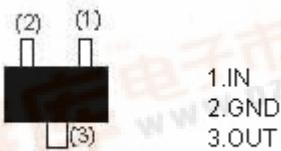
1. Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
2. The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
3. Only the on/off conditions need to be set for operation, making device design easy.

● Equivalent circuit



PIN CONNECTIONS AND MARKING

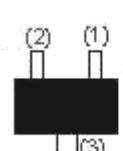
DTA114YE



SOT-523

Addreviated symbol: 54

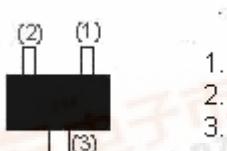
DTA114YUA



SOT-323

Addreviated symbol: 54

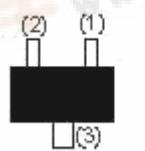
DTA114YKA



SOT-23-3L

Addreviated symbol: 54

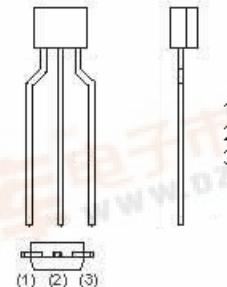
DTA114YCA



SOT-23

Addreviated symbol: 54

DTA114YSA



TO-92S

Absolute maximum ratings(Ta=25°C)

Parameter	Symbol	Limits (DTA114Y□)					Unit
		E	UA	KA	CA	SA	
Supply voltage	V _{CC}	-50					V
Input voltage	V _{IN}	-40 to +6					V
Output current	I _O	-70					mA
	I _{C(Max.)}	-100					mA
Power dissipation	P _C	150	200	300			mW
Junction temperature	T _J	150					°C
Storage temperature	T _{STG}	-55 to +150					°C

Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ	Max.	Unit	Conditions
Input voltage	V _{I(off)}			-0.3	V	V _{CC} =-5V , I _O =-100μA
	V _{I(on)}	-1.4				V _O =-0.3V , I _O =-1mA
Output voltage	V _{O(on)}			-0.3	V	I _O /I _I =-5mA/-0.25mA
Input current	I _I			-0.88	mA	V _I =-5V
Output current	I _{O(off)}			-0.5	μA	V _{CC} =-50V , V _I =0
DC current gain	G _I	68				V _O =-5V , I _O =-5mA
Input resistance	R _I	7	10	13	KΩ	
Resistance ratio	R ₂ /R ₁	3.7	4.7	5.7		
Transition frequency	f _T		250		MHz	V _O =-10V , I _O =5mA,f=100MHz

Typical Characteristics

●Electrical characteristic curves

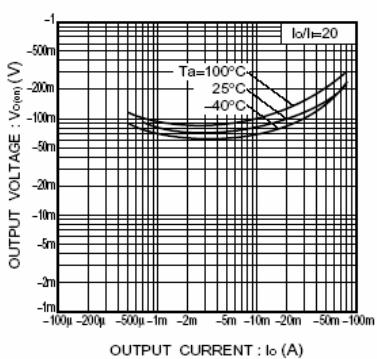
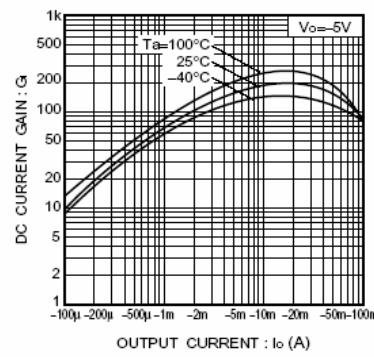
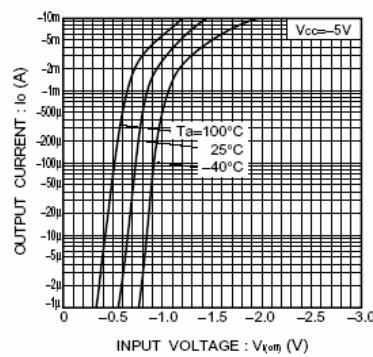
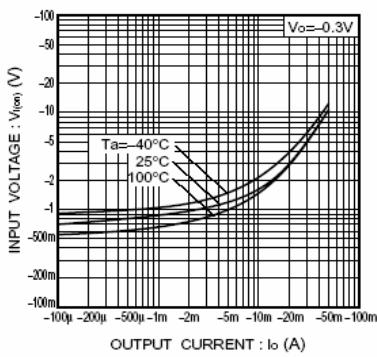


Fig.4 Output voltage vs. output current (Io/Ii = 20)